

20 V, single P-channel Trench MOSFET 19 June 2014

**Product data sheet** 

### 1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a small SOT457 (SC-74) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

### 2. Features and benefits

- Fast switching
- Trench MOSFET technology
- 2 kV ESD protection
- AEC-Q101 qualified

### 3. Applications

- Relay driver
- High-speed line driver
- High-side loadswitch
- Switching circuits

### 4. Quick reference data

Table 1. Qui	ck reference data						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>amb</sub> = 25 °C		-	-	-20	V
V <sub>GS</sub>	gate-source voltage			-12	-	12	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = -4.5 V; T <sub>amb</sub> = 25 °C; t ≤ 5 s	[1]	-	-	-5.7	А
Static characteristics							
R <sub>DSon</sub>	drain-source on-state resistance	V <sub>GS</sub> = -4.5 V; I <sub>D</sub> = -3 A; T <sub>j</sub> = 25 °C		-	27	30	mΩ

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

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# 5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	D	drain		D
2	D	drain		
3	G	gate		G ( T
4	S	source	TSOP6 (SOT457)	
5	D	drain		
6	D	drain	-	S 017aaa259

### 6. Ordering information

Table 3. Ordering in	formation		
Type number	Package		
	Name	Description	Version
PMN27XPEA	TSOP6	plastic surface-mounted package (TSOP6); 6 leads	SOT457

# 7. Marking

Table 4. Marking codes	
Type number	Marking code
PMN27XPEA	BD

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### 8. Limiting values

#### Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

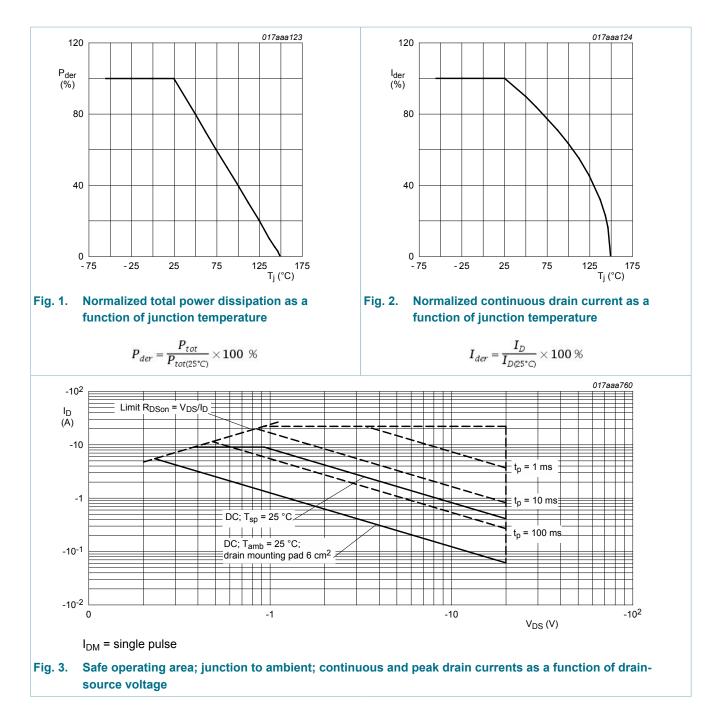
Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>amb</sub> = 25 °C		-	-20	V
V <sub>GS</sub>	gate-source voltage			-12	12	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = -4.5 V; T <sub>amb</sub> = 25 °C; t ≤ 5 s	[1]	-	-5.7	А
		V <sub>GS</sub> = -4.5 V; T <sub>amb</sub> = 25 °C	[1]	-	-4.4	А
		V <sub>GS</sub> = -4.5 V; T <sub>amb</sub> = 100 °C	[1]	-	-3.5	А
I <sub>DM</sub>	peak drain current	$T_{amb}$ = 25 °C; single pulse; $t_p \le 10 \ \mu s$		-	-22	А
P <sub>tot</sub> total power dissipation	total power dissipation	T <sub>amb</sub> = 25 °C	[2]	-	530	mW
			[1]	-	1250	mW
		T <sub>sp</sub> = 25 °C		-	8330	mW
Tj	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
Source-dra	in diode					
I <sub>S</sub>	source current	T <sub>amb</sub> = 25 °C	[1]	-	-1.3	А
ESD maxim	num rating					
V <sub>ESD</sub>	electrostatic discharge voltage	НВМ	[3]	-	2000	V

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[3] Measured between all pins.

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### 9. Thermal characteristics

Table 6.	Thermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R <sub>th(j-a)</sub> thermal resistance	in free air	[1]	-	206	237	K/W	
	from junction to ambient		[2]	-	86	100	K/W
ampient			[3]	-	52	60	K/W

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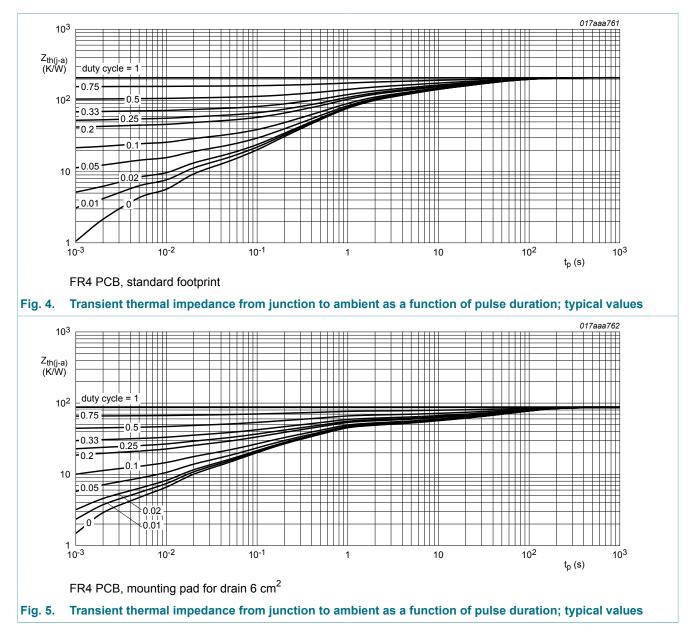
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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
R <sub>th(j-sp)</sub>	thermal resistance from junction to solder point		-	13	15	K/W

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>

[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>, t  $\leq$  5 s

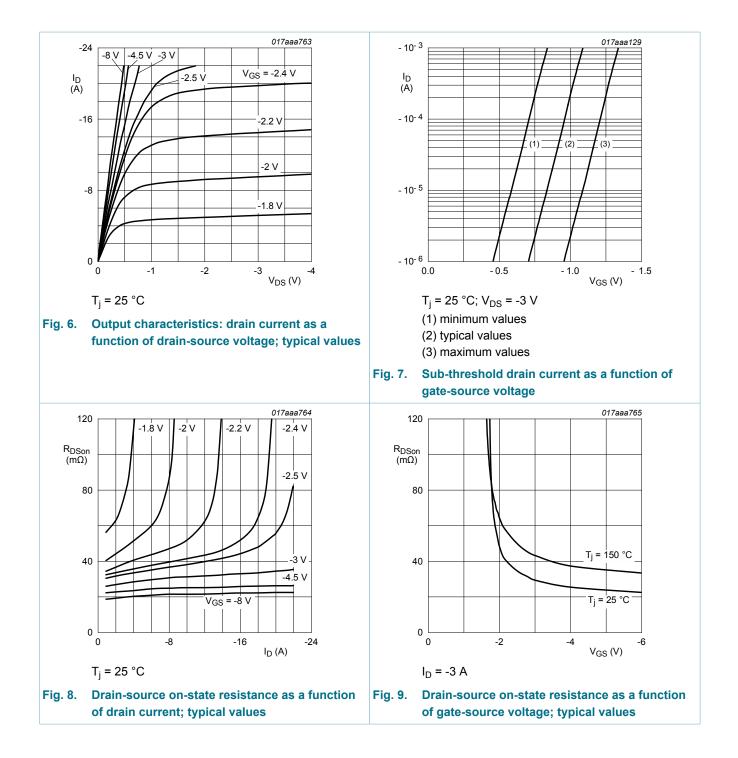


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### **10. Characteristics**

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static char	acteristics					
V <sub>(BR)DSS</sub>	drain-source breakdown voltage	$I_D$ = -250 µA; $V_{GS}$ = 0 V; $T_j$ = 25 °C	-20	-	-	V
V <sub>GSth</sub>	gate-source threshold voltage	$I_D$ = -250 µA; $V_{DS}$ = $V_{GS}$ ; $T_j$ = 25 °C	-0.75	-1	-1.25	V
I <sub>DSS</sub>	drain leakage current	$V_{DS}$ = -20 V; $V_{GS}$ = 0 V; $T_j$ = 25 °C	-	-	-1	μA
I <sub>GSS</sub> gate leakage current		$V_{GS}$ = 12 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	10	μA
		$V_{GS}$ = -12 V; $V_{DS}$ = 0 V; $T_j$ = 25 °C	-	-	-10	μA
R <sub>DSon</sub>	drain-source on-state	$V_{GS}$ = -4.5 V; I <sub>D</sub> = -3 A; T <sub>j</sub> = 25 °C	-	27	30	mΩ
	resistance	$V_{GS}$ = -4.5 V; I <sub>D</sub> = -3 A; T <sub>j</sub> = 150 °C	-	56	64	mΩ
		$V_{GS}$ = -2.5 V; I <sub>D</sub> = -3 A; T <sub>j</sub> = 25 °C	-	39	44	mΩ
9 <sub>fs</sub>	forward transconductance	V <sub>DS</sub> = -10 V; I <sub>D</sub> = -3 A; T <sub>j</sub> = 25 °C	-	16	-	S
Dynamic cl	naracteristics					
Q <sub>G(tot)</sub>	total gate charge	$V_{DS}$ = -10 V; I <sub>D</sub> = -3 A; V <sub>GS</sub> = -4.5 V;	-	15	22.5	nC
Q <sub>GS</sub>	gate-source charge	T <sub>j</sub> = 25 °C	-	3	-	nC
Q <sub>GD</sub>	gate-drain charge		-	3	-	nC
C <sub>iss</sub>	input capacitance	$V_{DS}$ = -10 V; f = 1 MHz; $V_{GS}$ = 0 V;	-	1770	-	pF
C <sub>oss</sub>	output capacitance	T <sub>j</sub> = 25 °C	-	254	-	pF
C <sub>rss</sub>	reverse transfer capacitance		-	180	-	pF
t <sub>d(on)</sub>	turn-on delay time	$V_{DS}$ = -10 V; I <sub>D</sub> = -3 A; V <sub>GS</sub> = -4.5 V;	-	15	-	ns
t <sub>r</sub>	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 °C$	-	22	-	ns
t <sub>d(off)</sub>	turn-off delay time		-	37	-	ns
t <sub>f</sub>	fall time		-	29	-	ns
Source-dra	in diode		I			
V <sub>SD</sub>	source-drain voltage	I <sub>S</sub> = -1.3 A; V <sub>GS</sub> = 0 V; T <sub>i</sub> = 25 °C	-	-0.7	-1.2	V

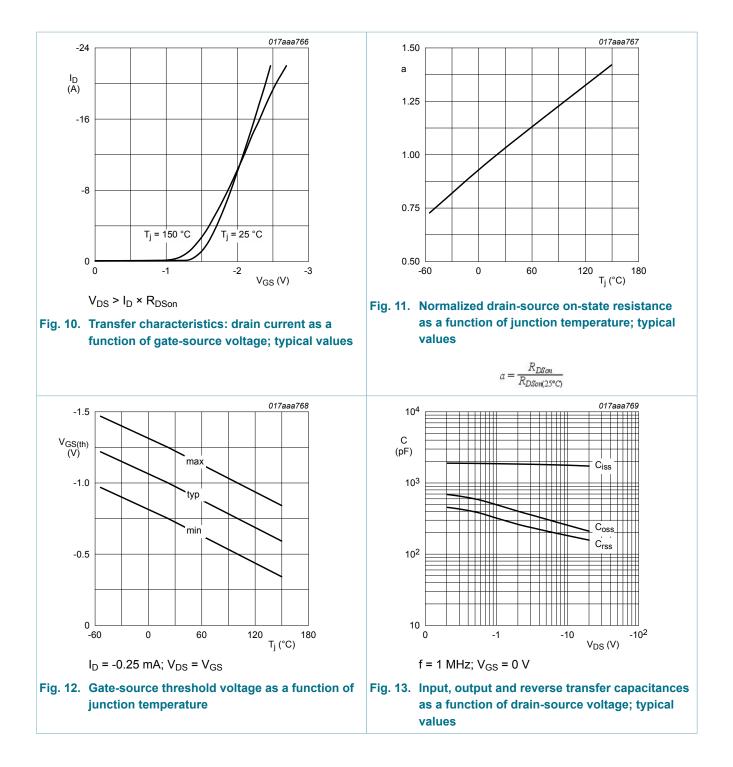
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# **PMN27XPEA**

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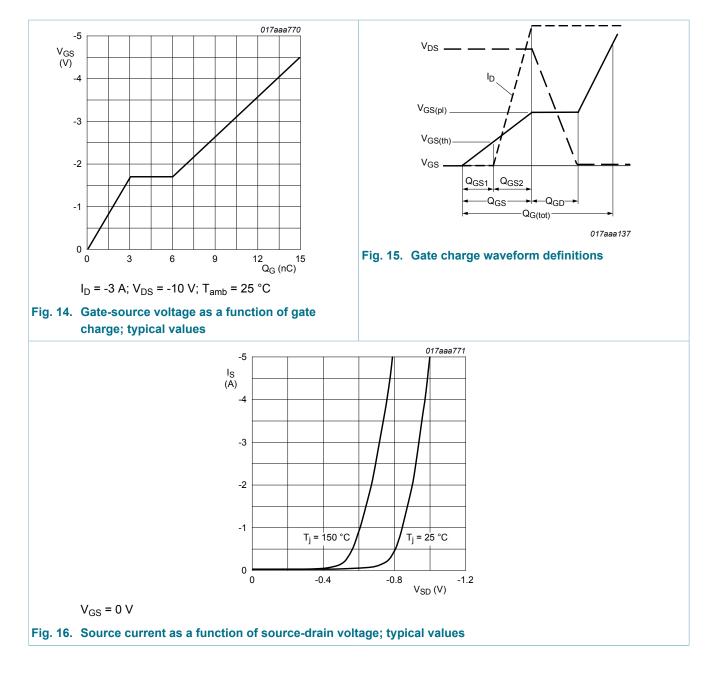


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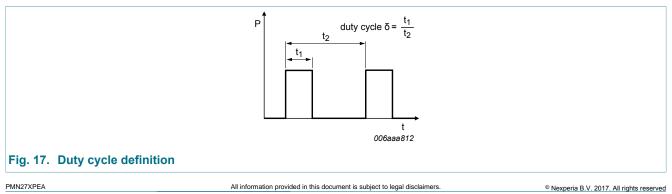
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# **PMN27XPEA**

#### 20 V, single P-channel Trench MOSFET



### **11. Test information**



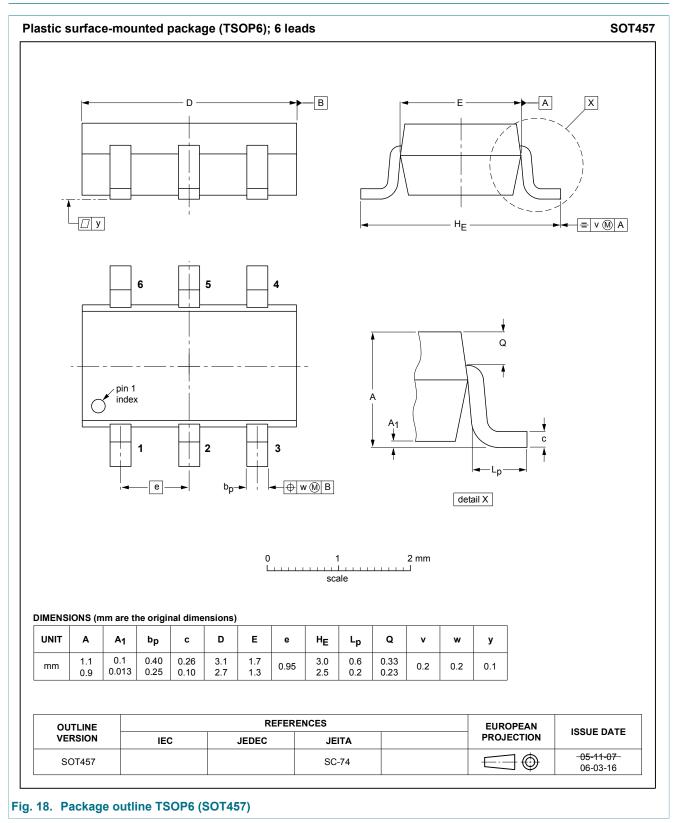
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### **11.1 Quality information**

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

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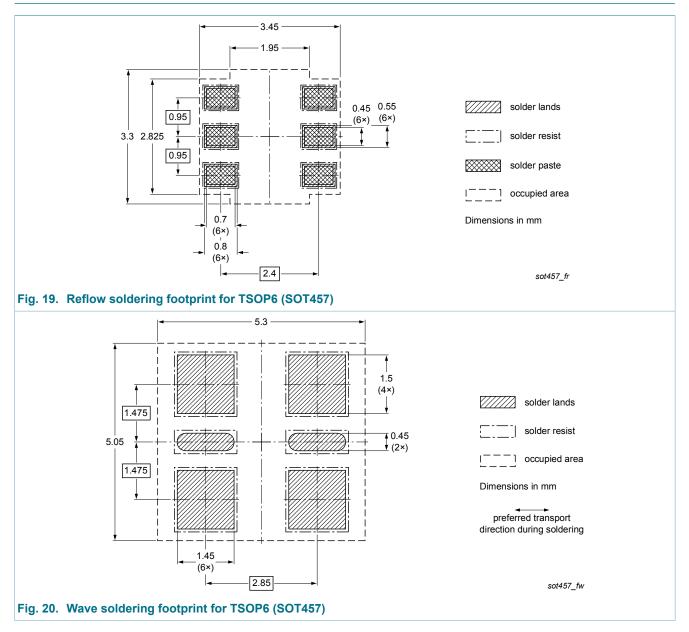
### 12. Package outline



**Product data sheet** 

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### **13. Soldering**



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# 14. Revision history

Table 8. Revision history				
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMN27XPEA v.1	20140619	Product data sheet	-	-

#### 20 V, single P-channel Trench MOSFET

### 15. Legal information

#### 15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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